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APPL NO.	FILING OR 371 (c) DATE	ART UNIT	FIL FEE REC'D	ATTY. DOCKET NO	DRAWINGS	TOT CLMS	IND CLMS
10/718,877	11/21/2003	2811	1234	TS02-622	5	41	4

CONFIRMATION NO. 1485

GEORGE O. SAILE
 28 DAVIS AVENUE
 POUGHKEEPSIE, NY 12603

FILING RECEIPT



OC000000011940930

Date Mailed: 02/20/2004

Receipt is acknowledged of this regular Patent Application. It will be considered in its order and you will be notified as to the results of the examination. Be sure to provide the U.S. APPLICATION NUMBER, FILING DATE, NAME OF APPLICANT, and TITLE OF INVENTION when inquiring about this application. Fees transmitted by check or draft are subject to collection. Please verify the accuracy of the data presented on this receipt. If an error is noted on this Filing Receipt, please write to the Office of Initial Patent Examination's Filing Receipt Corrections, facsimile number 703-746-9195. Please provide a copy of this Filing Receipt with the changes noted thereon. If you received a "Notice to File Missing Parts" for this application, please submit any corrections to this Filing Receipt with your reply to the Notice. When the USPTO processes the reply to the Notice, the USPTO will generate another Filing Receipt incorporating the requested corrections (if appropriate).

Applicant(s)

Shih Wei Wang, Hsin Chu, TAIWAN;
 Chia-Dar Hsieh, Science-Based Industrial Park, TAIWAN;

Assignment For Published Patent Application

Taiwan Semiconductor Manufacturing Co.;

Domestic Priority data as claimed by applicant

Foreign Applications

If Required, Foreign Filing License Granted: 02/20/2004

Projected Publication Date: 05/26/2005

Non-Publication Request: No

Early Publication Request: No

Title

Endurance improvement by sidewall nitridation of poly floating gate for nonvolatile memory devices using substrate or drain-side erase scheme

Preliminary Class

257

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Title 35, United States Code, Section 184
Title 37, Code of Federal Regulations, 5.11 & 5.15**

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GEORGE O. SAILE & ASSOCIATES
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TS02-622

March 3, 2004

To: Mail Stop: Application Number
Commissioner For Patents
P.O. Box 1450
Alexandria, VA 22313-1450

From: Stephen B. Ackerman

Subject: Serial No.: 10/718,877
Filing Date: 11/21/03
Inventor: S. W. Wang, et al
Title: Endurance Improvement by Sidewall Nitridation of Poly
Floating Gate for Nonvolatile Memory Devices Using Substrate
or Drain-Side Erase Scheme

REQUEST TO CORRECT FILING RECEIPT

Dear Sir:

On the copy of the enclosed Filing Receipt, there is an error in the list of Applicants. The second Applicant's residence is misspelled. Mr. Hsieh's name and corrected residence reads; **Chia-Dar Hsieh, Tainan, Taiwan.**

Please make the necessary change to correct the error on the Filing Receipt.

If there are any questions, please contact the undersigned attorney at (845) 452-5863. Thank you for your attention to this matter.

Respectfully Submitted,

Stephen B. Ackerman, Reg. No. 37,761